2<sup>nd</sup> Semester

Paper: Digital Electronics (BIT - 201)

Time Allowed: 2 1/2 Hours

May - 2011

Maximum Marks: 80

Min Pass Marks: 32

Note:- Attempt all questions from Section A & B and only Two questions from Section C.

Section 14: Very short answer type questions to be answered in about 20 words (Marks:2x8=16)

Solve in binary

 $(1-1001)_2 \times (10.101)_2 - (1.0101)_2$ 

il Why are NAND and NOR gates called Universal gates? iii)

What is the difference between product term and min-term? iv)

W Draw the circuit of an SR flip flop with NOR gates?

vi) Define Up-down counter?

vii) What is meant by distractive read-out?

viii) Draw the circuit for a dynamic MOS RAM cell.

Section B: Short answer type questions to be answered in about 250 words (Marks:  $4 \times 8 = 32$ )

2. Draw the circuit for a two-input RTL gate and explain its working?

3. Minimize the following Boolean expression using K-map

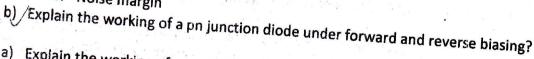
 $f(a,b,c,d) = \sum (1,2,3,5,13) + \sum d(6,7,8,9,10,11)$ 

4. Draw and explain a clocked SR flip flop?

5. Explain how two 16x4 RAMs can be connected to form one 16x8 RAM?

Section C: Long answer type questions to be answered in about 500words (Marks:2x 16 =32)

- a) Define the terms:
  - i. Fan-in
  - ii. Fan-out
  - iii. Propagation Delay
  - iv. Noise margin



- a) Explain the working of a multiplexer?
- b) Realize the following function with a 8:1 multiplexer.
- 8. Discuss the design of a synchronous decade counter using T-flip flops and show output
- a) Explain linear and coincident selection in a RAM?
- b) Draw the circuit for a dynamic shift register cell and explain its operation?

m = ~ 200